

Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-25	V
Emitter-Base Voltage	V _{EBO}	-4.0	V
Collector Current	Ic	-200	mA

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	3°

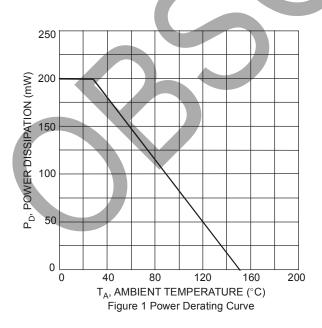
ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information





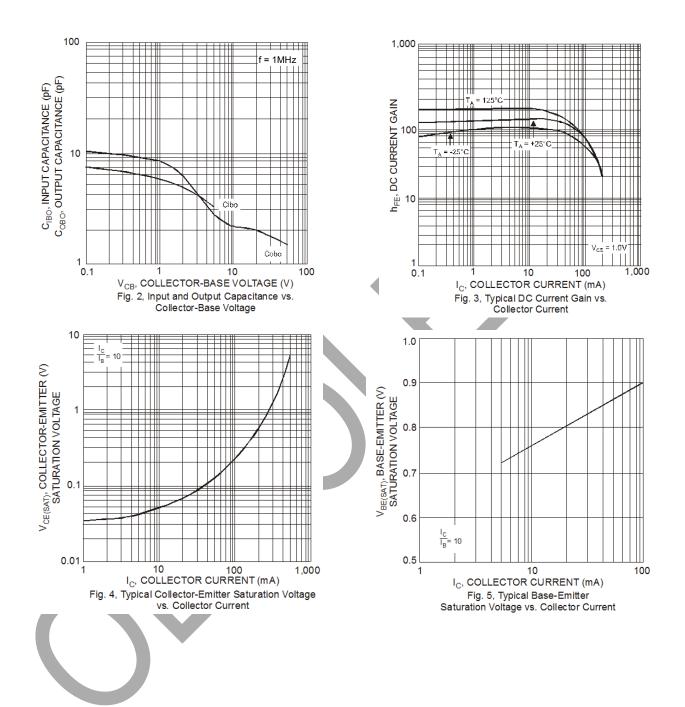
Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						•
Collector-Base Breakdown Voltage	BV CBO	-25	_	_	V	I _C = -10μA, I _B = 0
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-25	—	_	V	I _C = -10mA, I _B = 0
Emitter-Base Breakdown Voltage	BV _{EBO}	-4.0	_	—	V	I _E = -10μA, I _C = 0
Collector Cut-Off Current	I _{CBO}	-	_	-50	nA	$V_{CB} = -20V, I_E = 0$
Collector Cut-Off Current	I _{EBO}	_	_	-50	nA	V _{EB} = -3.0V, I _C = 0
ON CHARACTERISTICS (Note 7)						
DC Current Gain	b	120	—	360		I _C = -2.0mA, V _{CE} = -1.0V
	h _{FE}	60	—	—		I _C = -50mA, V _{CE} = -1.0V
Collector-Emitter Saturation Voltage	VCE(SAT)			-0.4	V	$I_{C} = -50 \text{mA}, I_{B} = -5.0 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	_	-0.95	V	I _C = -50mA, I _B = 5.0mA
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{OBO}			4.5	pF	V _{CB} = -5.0V, f = 1.0MHz, I _E = 0
Input Capacitance	CIBO			10	pF	V_{EB} = -0.5V, f = 1.0MHz, I _C = 0
Small Signal Current Gain	h _{FE}	120	—	480	-	V_{CE} = -1.0V, I _C = -2.0mA, f = 1.0kHz
Current Gain Bandwidth Product	f _T	250	-		MHz	V _{CE} = -20V, I _C = -10mA, f = 100MHz
Noise Figure	NF	_	-	4.0	dB	V_{CE} = -5.0V, I _C = -100µA, R _S = 1.0kΩ, f = 1.0kHz

Note: 7. Short duration pulse test used to minimize self-heating effect.



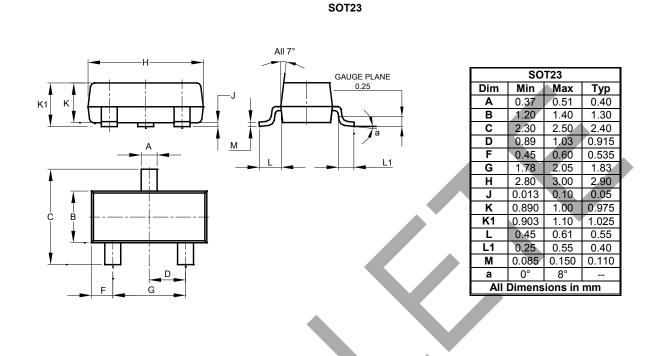
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

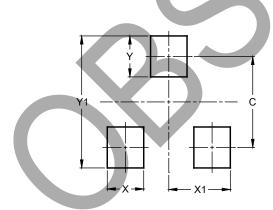
Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

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